

DR8 PIC with Differential Drive

- ▶ Requires 1.5 V_{pp} differential swing to achieve a 5 dB modulated ER
- ▶ Ideal for direct drive from DSPs with integrated drivers
- ▶ Features >130 GHz 3 dB electro-optic bandwidth

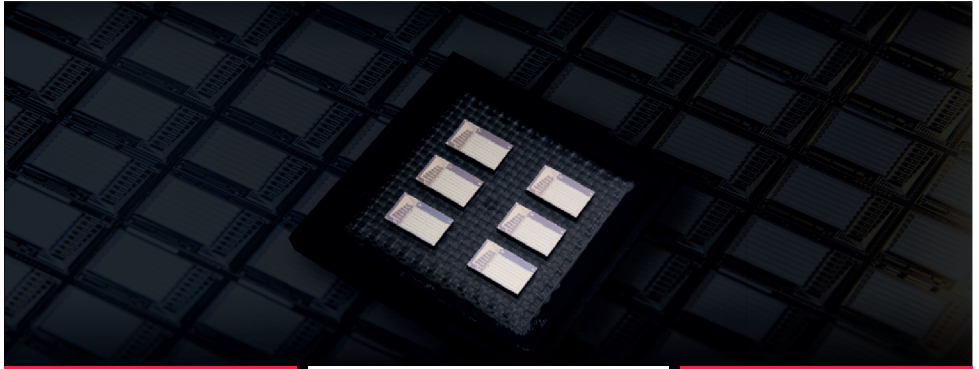
DR8 PIC with Single-Ended Drive

- ▶ Requires 1.4 V_{pp} single-ended swing to achieve a 5 dB modulated ER
- ▶ Ideal for use with linear drivers such as single-ended DSP or LPO
- ▶ Featuring >150 GHz 3 dB electro-optic bandwidth

Contact Us For More Information:

- ▶ Product Briefs
- ▶ Application Notes
- ▶ PIC Samples
- ▶ Custom chip development





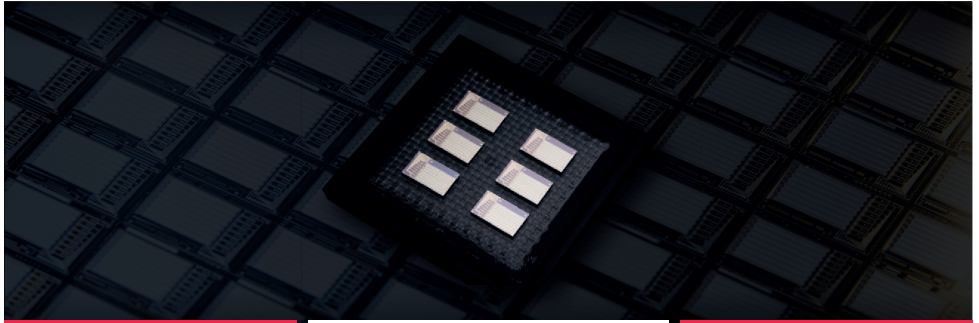
DR8 PIC with Differential Drive (Ultra-Low Power)

- ▶ Requires 0.6 Vpp differential swing to achieve a 5 dB modulated ER
- ▶ Designed for direct drive from DSPs without an integrated driver, ensuring ultra-low power consumption

Key Features:

- ▶ Reliable & qualified
- ▶ Supports single or dual input laser to drive all 8-channels
- ▶ CMOS-level drive voltage, featuring our patented ultra-low drive voltage design
- ▶ > 110 GHz electro-optic bandwidth
- ▶ Low total optical insertion loss
- ▶ Robust optical interface to single-mode fibers
- ▶ Known-Good-Die (KGD) or wafer delivery option
- ▶ Comprehensive end-to-end customer support





130 GBaud DPIQ PIC

HyperLight's **130 GBaud DPIQ PICs** are custom designed for CDM and ZR applications, featuring high-bandwidth and low voltage modulators, compatible with a large variety of linear drivers.

Custom DPIQ PICs

- ▶ 130, 200, 260 GBaud designs
- ▶ Low V_{π}
- ▶ Low optical loss
- ▶ Single-ended or differential electrodes
- ▶ Customized I/O interfaces and formfactor, suitable for HB-CDM, QSFP-DD ZR/ZR+ etc.

Key Features:

- ▶ Reliable and Qualified
- ▶ Patented ultra-low drive voltage design
- ▶ >110 GHz electro-optic bandwidth
- ▶ Low total optical insertion loss
- ▶ Integrated polarization multiplexing
- ▶ Robust interface to single-mode fibers
- ▶ Known-Good-Die (KGD) delivery
- ▶ Strong end-to-end customer support

Contact Us For More Information:

- ▶ Product Briefs
- ▶ Application Notes
- ▶ PIC Samples
- ▶ Custom chip development





110 GHz Intensity Modulator

Key Features:

- ▶ Proven Production Grade 110 GHz EOM
- ▶ > 125 GHz bandwidth
- ▶ Industries' lowest half-wave voltage

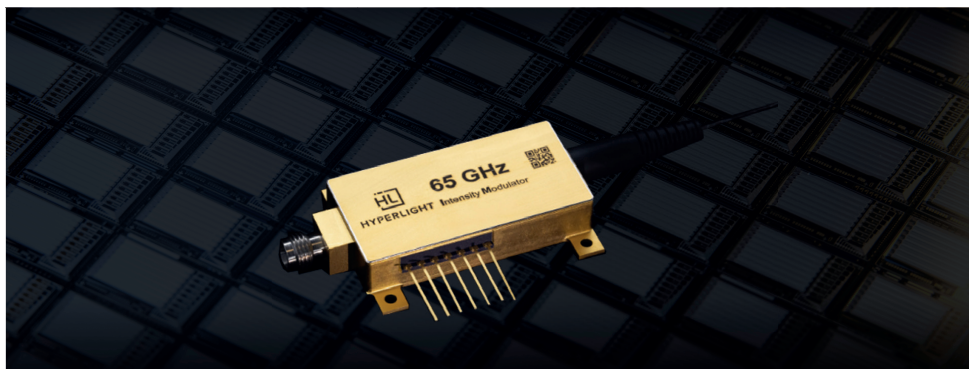
NEW - **1.4V** Low V_{π} version available!

- ▶ Compact footprint
- ▶ High extinction ratio
- ▶ Stable DC biasing
- ▶ High optical and RF power handling
- ▶ 1.0 mm RF Connector (W), PM fibers with FC/APC connectors
- ▶ C/L-band, O-band, 1 μ m Coverage
- ▶ Bias controller available
- ▶ **NEW** - **Cryogenic-compatible** version available!

Target Applications:

- ▶ 448 G/lane testing
- ▶ 240 GBaud testing
- ▶ Reference transmitters for test and measurement
- ▶ Radio-over-fiber and satellite links





65 GHz Intensity Modulator

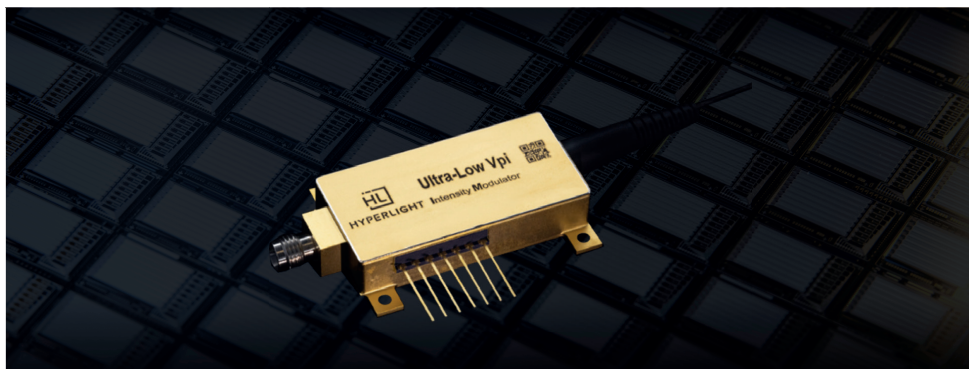
Key Features:

- ▶ > 70 GHz operating bandwidth
- ▶ 1.4 V half-wave voltage
- ▶ V-type (1.85 mm) connector
- ▶ Compact footprint
- ▶ High extinction ratio
- ▶ Stable DC biasing
- ▶ High optical and RF power handling
- ▶ **NEW - Cost-effective** version available!
- ▶ C/L-band, O-band, 1 μ m Coverage
- ▶ Bias controller available

Target Applications:

- ▶ 200 G/lane testing
- ▶ 150 GBaud testing





Ultra-Low V_{π} Intensity Modulator

Key Features:

- ▶ > 40 GHz bandwidth
- ▶ 0.7 V half-wave voltage
- ▶ Compact footprint
- ▶ High extinction ratio
- ▶ Stable DC biasing
- ▶ High optical and RF power handling
- ▶ Dual outputs for balanced detection

Target Applications:

- ▶ Radio-over-fiber and satellite links
- ▶ Wireless
- ▶ 5G/6G





110 GHz Phase Modulator

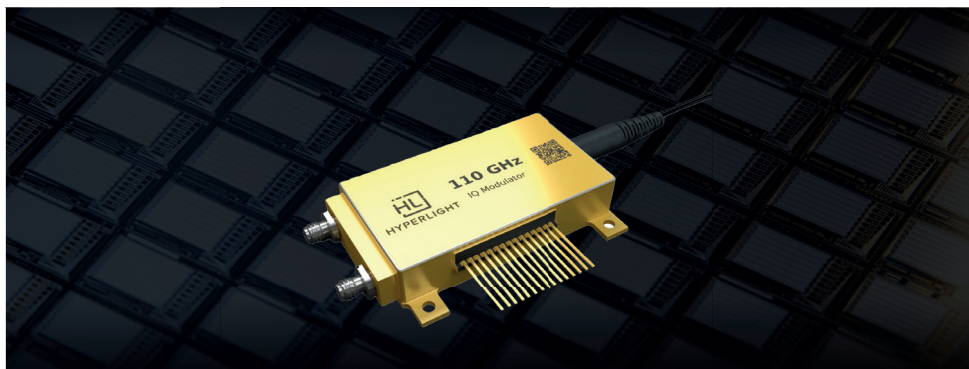
Key Features:

- ▶ > 110 GHz bandwidth
- ▶ Record low V_{pi}
- ▶ W-type (1.0 mm) connectors
- ▶ High optical and RF power handling

Target Applications:

- ▶ Optical computing
- ▶ Quantum communication
- ▶ Microwave photonics
- ▶ Electro-optical comb generation





110 GHz IQ Modulator

Key Features:

- ▶ Single-polarization IQ modulator
- ▶ > 125 GHz bandwidth
- ▶ Supports 240 GBaud signaling
- ▶ Fully packaged with two W-type (1.0 mm) connectors
- ▶ IQ bias controller available
- ▶ C/L-band, O-band coverage

Target Applications:

- ▶ 240 GBaud testing
- ▶ 110 GHz single sideband modulation



COMING SOON

145 GHz Intensity Modulator

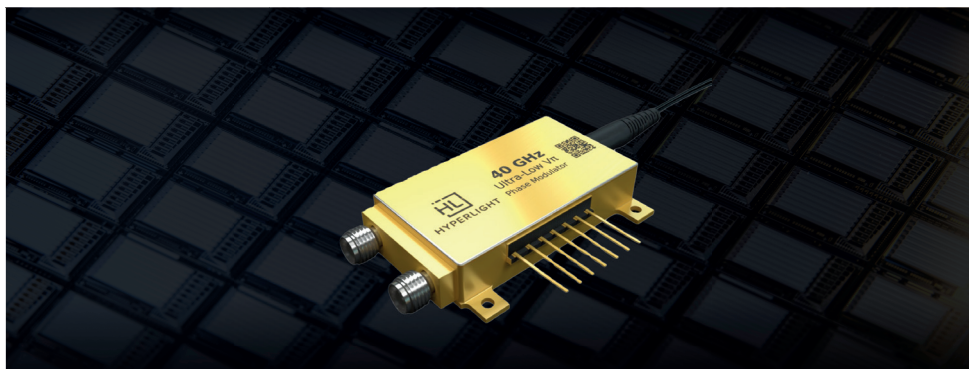
Key Features:

- ▶ > 145 GHz bandwidth
- ▶ 0.8mm connector
- ▶ High extinction ratio
- ▶ Stable DC biasing
- ▶ High optical and RF power handling

Target Applications:

- ▶ 260 GBaud testing
- ▶ 140 GBaud testing
- ▶ 70 GHz single sideband modulation





40 GHz Ultra-Low V_{π} Phase Modulator

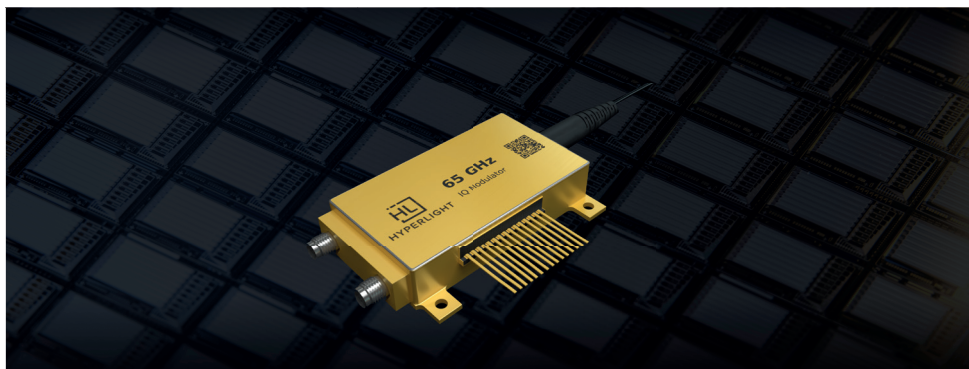
Key Features:

- ▶ Ultra-low half-wave voltage
- ▶ External termination for high **5W** RF power handling
- ▶ > 40 GHz EO bandwidth
- ▶ High optical power handling
- ▶ Simplified single-piece modulator solution for EO comb generation

Target Applications:

- ▶ Electro-optical comb generation
- ▶ Quantum measurements
- ▶ Microwave photonics





65 GHz IQ Modulator

Key Features:

- ▶ Single-polarization IQ modulator
- ▶ > 70 GHz bandwidth
- ▶ Supports 140 GBaud signaling
- ▶ Fully packaged gold box with two V-type (1.85 mm) connectors
- ▶ IQ bias controller available to 65 GHz IQ
- ▶ C/L-band, O-band coverage

Target Applications:

- ▶ 140 GBaud testing
- ▶ 70 GHz single sideband modulation

